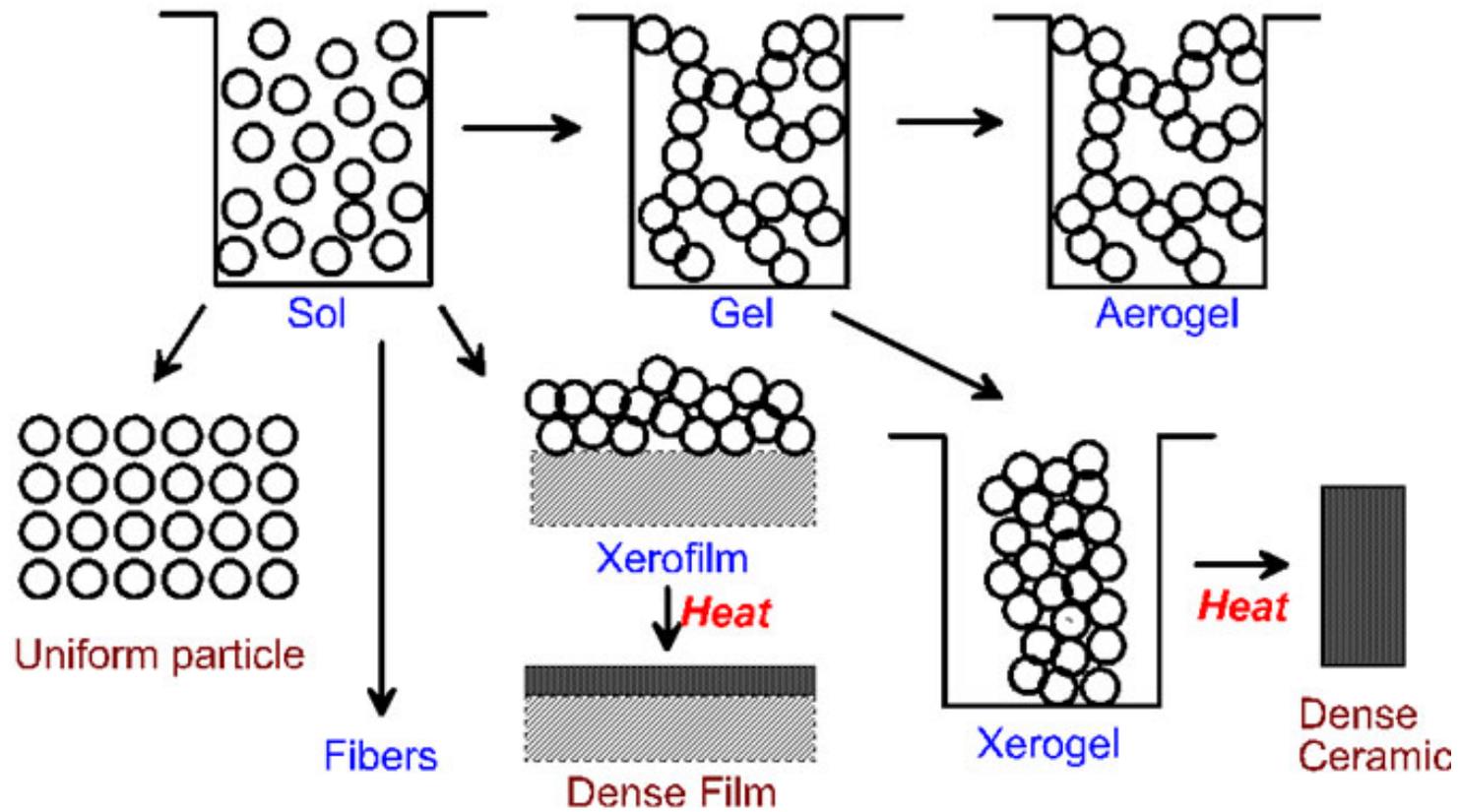


X. Applications of Sol-Gel Method

Overview of the sol-gel process



- Thin Films and Coatings

- Optical coating

Titania films on glass (silica) surface



- Electronic films

High Tc superconductor films

Titania films for photoanode

Yttria/zirconia films for electrolytes



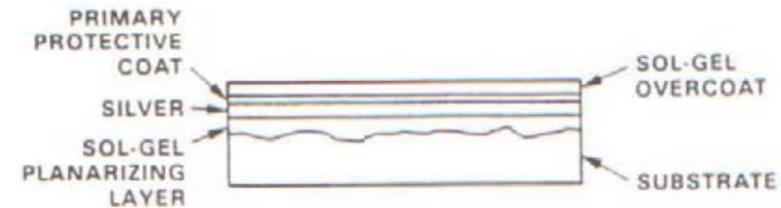
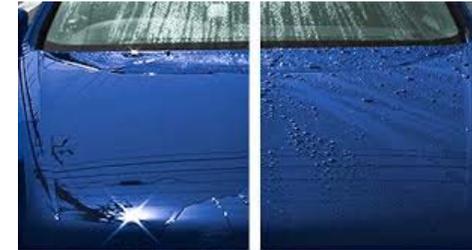
· Protective films

To improve corrosion and abrasion resistance

To promote adhesion

To increase strength

To provide planarization



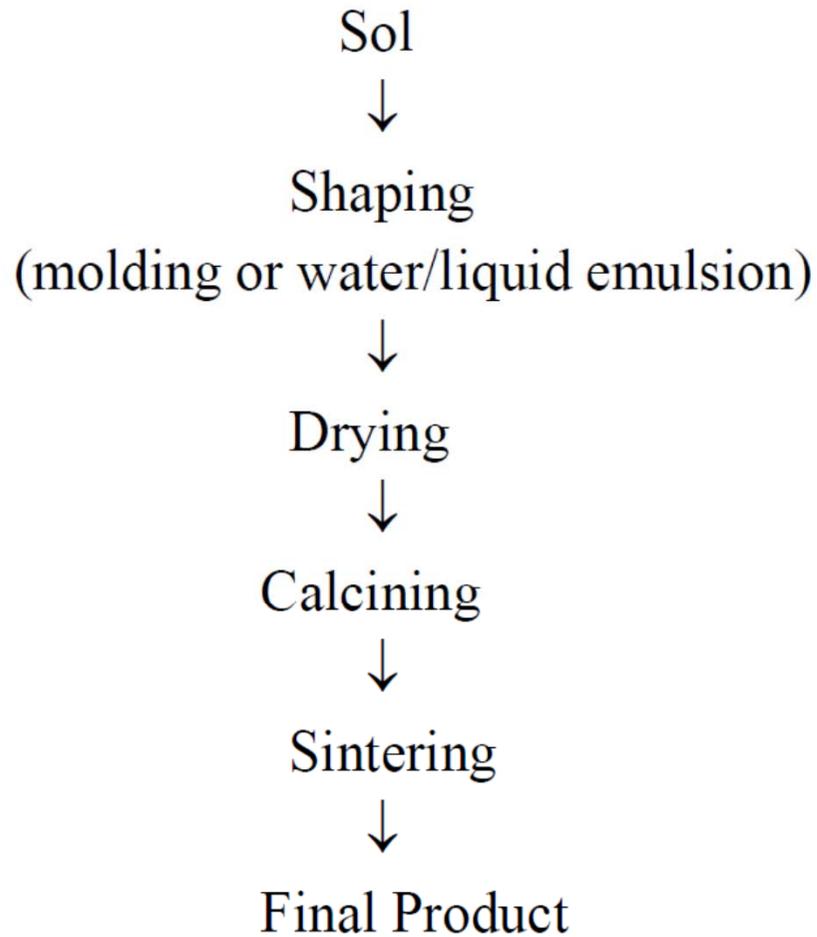
· Porous films

Zeolite crystalline films embedded on silicate sol-gel matrices

for surface acoustic wave device



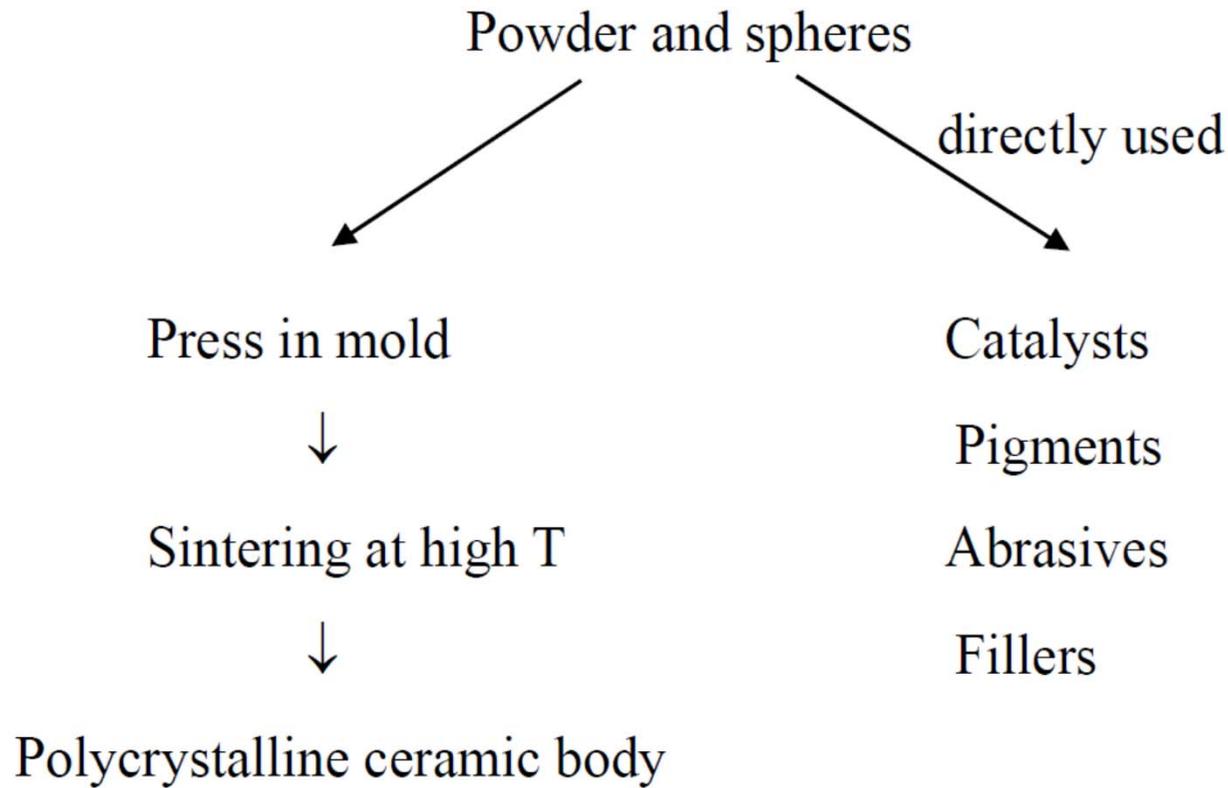
- Monoliths (dimension > 1 mm)



- Optical glasses and fiber-optic preforms
- Aerogel transparent insulation
- Substrates
- Near netshape optical components
- Adsorbent granules



- Powder and Spheres



- Fibers

- Not appropriate for optical fiber applications (noncircular cross-section)
- But potential applications as

Reinforcement fibers

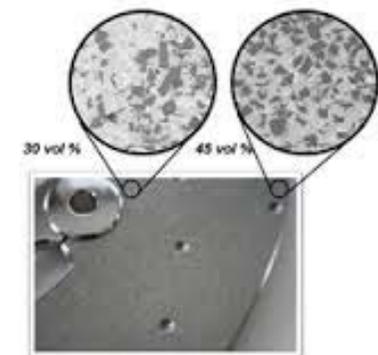
High T_c superconductor fibers

Refractory textile

- Composites

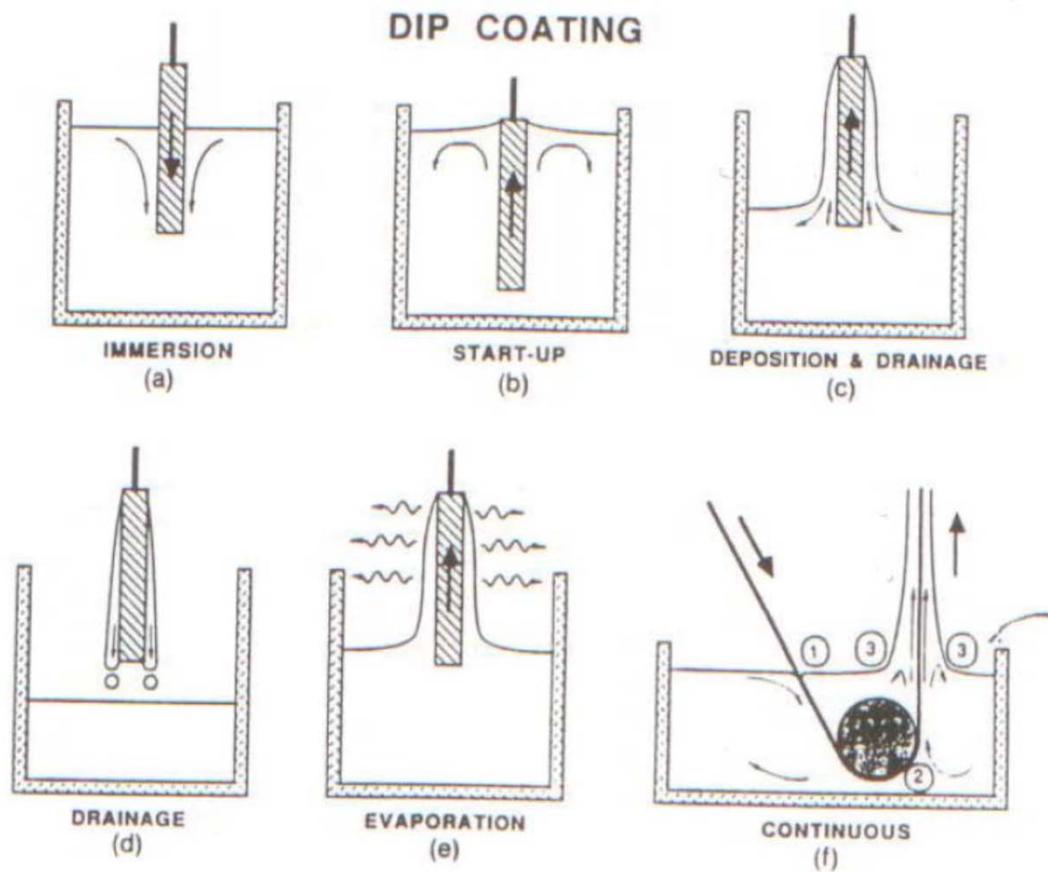
- Fiber-reinforced sol-gel matrix
- Ceramic-ceramic or ceramic-metal composite
- Glass or ceramic-organic

e.g. SiC reinforced alumina (for turbine blades)

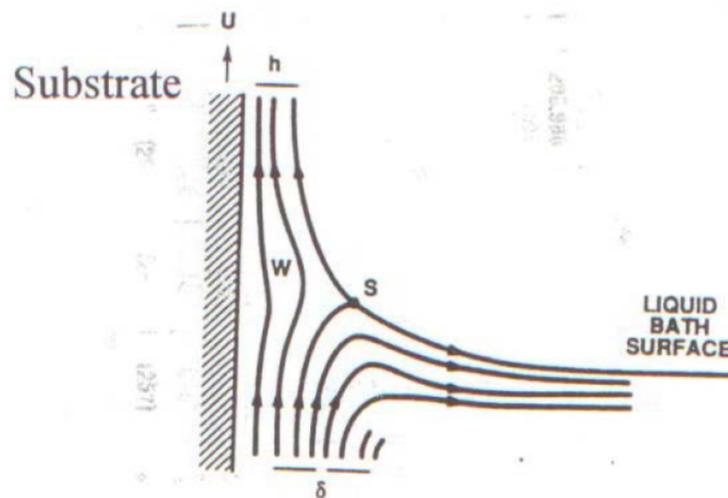


FILM-FORMATION BY SOL-GEL METHOD

- Dip-Coating: Film coating (on dense substrate)



Detail of liquid flow pattern at point (c)



U: withdraw speed

s: stagnation point

δ : boundary layer

h: thickness of fluid film

Six forces involved in this dip-coating process

- (1) Viscous drag upward on the liquid by the moving substrate
- (2) Gravity
- (3) Surface tension in the concavely curved meniscus
- (4) Inertial force of the boundary layer liquid in the deposition region
- (5) Surface tension gradient
- (6) Disjoining or conjoining pressure

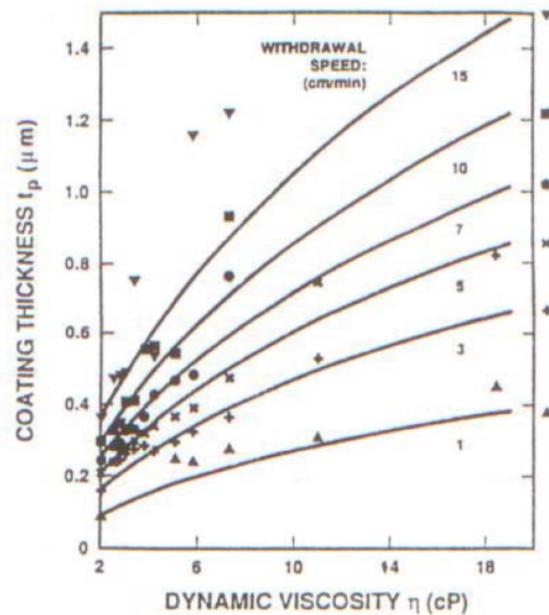


If only forces 1 and 2 are important, force balance gives:

$$\begin{array}{ccc} \mu U/h & = & c(\rho g h) \\ \uparrow & & \uparrow \\ \text{force (1)} & & \text{force (2)} \quad (c: \text{proportionality constant}) \end{array}$$

so

$$h = c' (\mu U / \rho g)^{1/2}$$

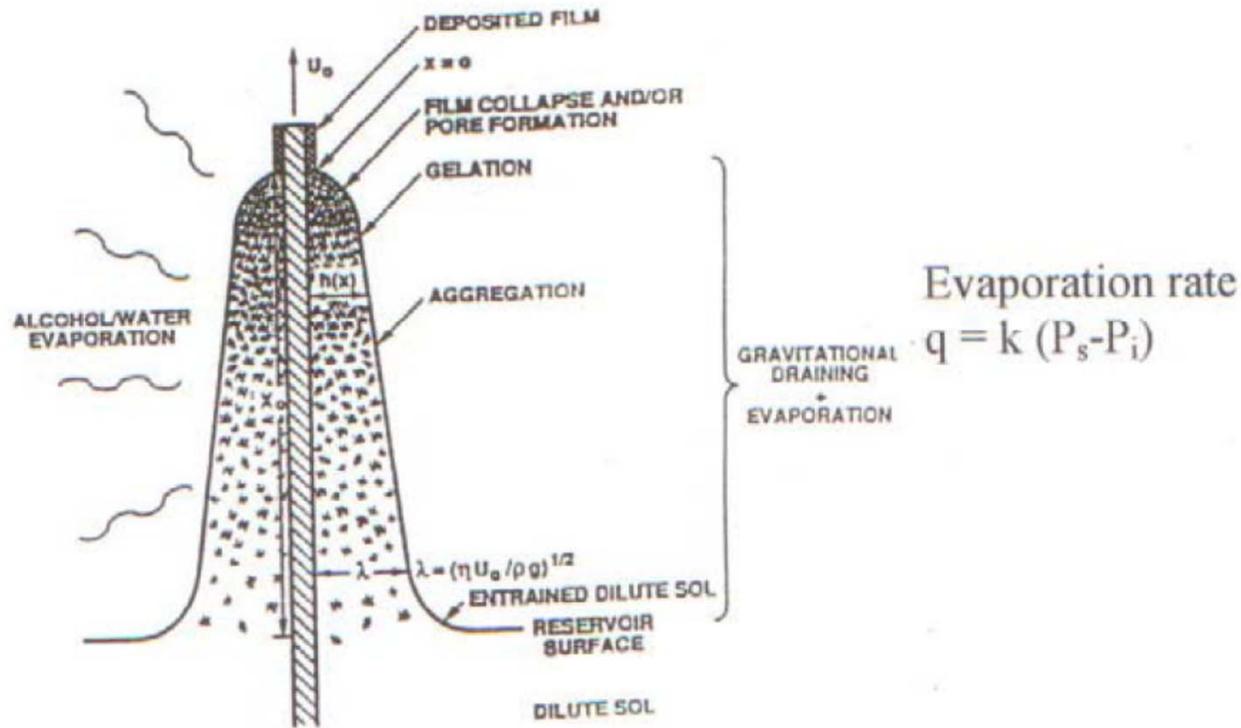


$$h \propto \mu^{1/2}$$

$$h \propto U^{1/2}$$

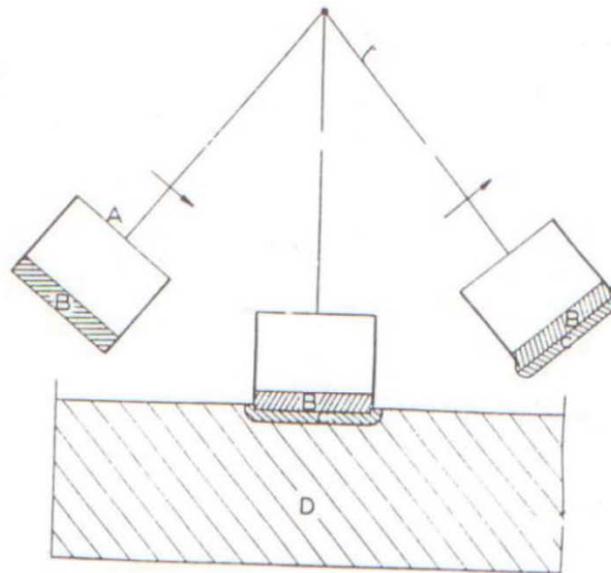


- Structural Evolution During Dip-Coating Process



- Dip-Coating: Slipcasting Process (on Porous Substrate)

The dip-coating process for ceramic membrane fabrication, with porous substrate.



$$\begin{aligned} \text{(Rate of Accumulation of Solid in the Gel Layer)} = \\ \text{(Solvent Flow Rate)} \times \text{(Concentration of Solid in the Sol)} \end{aligned}$$



(Rate of Accumulation of Solid in the Gel Layer) =

(Solvent Flow Rate) × (Concentration of Solid in the Sol)

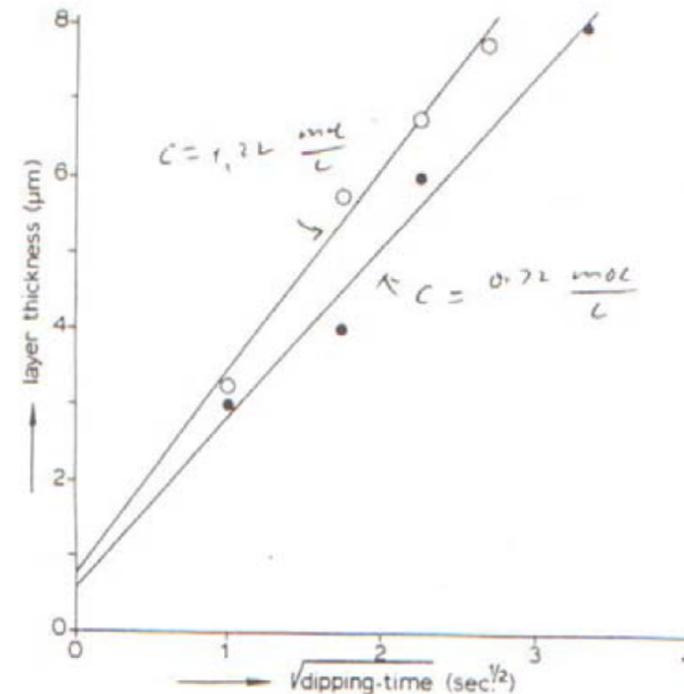
Thus, film thickness h is related to:

$$h \propto \left(\frac{C_s P_g t}{\mu} \right)^{1/2}$$

C_s : solid concentration in the sol

P_g : capillary pressure

t : dip-coating contact time



- Other Coating Method

Spin Coating

Centrifugal force =
Viscous force

